

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

**Applicant(s):** Kwang Choe, et al.

**Examiner:** Padgett, Marianne L.

**Serial No.:** 10/674,648

**Docket No.:** YOR920030294US1(16817)

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**Group Art Unit:** 1762

**Title:** SOI BY OXIDATION OF  
POROUS SILICON

**Date:** December 6, 2007

**Confirmation No.:** 4794

Mail Stop Amendment  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

**RESPONSE UNDER 37 C.F.R. §1.111**

Sir:

In response to the Office Action dated June 15, 2007 and the non-compliant amendment dated November 27, 2005, please amend the above-identified application as follows:

**Amendments to the Specification** begin on page 2 of this paper.

**Amendments to the Claims** are reflected in the listing of claims, which begin on page 3 of this paper.

**Remarks** begin on page 8 of this paper.

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**CERTIFICATE OF ELECTRONIC FILING**

I hereby certify that this correspondence is being deposited with the United States Patent & Trademark Office via Electronic Filing through the United States Patent and Trademark Office e-business website, on **December 6, 2007**.

**Dated: December 6, 2007**

  
Harry Andrew Hild Jr.